

# Enhancement of Efficiency of Perovskite Solar Cells with Hole-Selective Layers of Rationally Designed Thiazolo[5,4-*d*]thiazole Derivatives

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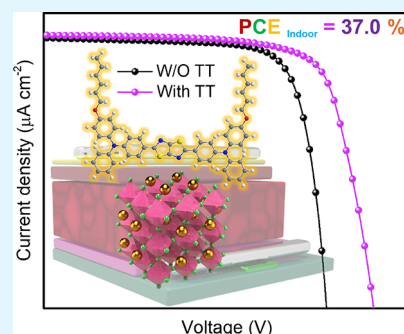
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**ABSTRACT:** We introduce thiazolo[5,4-*d*]thiazole (TT)-based derivatives featuring carbazole, phenothiazine, or triphenylamine donor units as hole-selective materials to enhance the performance of wide-bandgap perovskite solar cells (PSCs). The optoelectronic properties of the materials underwent thorough evaluation and were substantially fine-tuned through deliberate molecular design. Time-of-flight hole mobility TTs ranged from  $4.33 \times 10^{-5}$  to  $1.63 \times 10^{-3} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$  (at an electric field of  $1.6 \times 10^5 \text{ V cm}^{-1}$ ). Their ionization potentials ranged from  $-4.93$  to  $-5.59 \text{ eV}$ . Using density functional theory (DFT) calculations, it has been demonstrated that  $S_0 \rightarrow S_1$  transitions in TTs with carbazolyl or *ditert*-butyl-phenothiazinyl substituents are characterized by local excitation (LE). Mixed intramolecular charge transfer (ICT) and LE occurred for compounds containing *ditert*-butyl carbazolyl-, dimethoxy carbazolyl-, or alkoxy-substituted triphenylamino donor moieties. The selected derivatives of TT were used for the preparation of hole-selective layers (HSL) in PSC with the structure of glass/ITO/HSLs/ $\text{Cs}_{0.18}\text{FA}_{0.82}\text{Pb}(\text{I}_{0.8}\text{Br}_{0.2})_3$ /PEAI/PC<sub>61</sub>BM/BCP/Ag. The alkoxy-substituted triphenylamino containing TT (TTP-DPA) has been demonstrated to be an effective material for HSL. Its layer also functioned well as an interlayer, improving the surface of control HSL\_2PACz (i.e., reducing the surface energy of 2PACz from 66.9 to 52.4 mN m<sup>-1</sup>), thus enabling precise control over perovskite growth energy level alignment and carrier extraction/transportation at the hole-selecting contact of PSCs. 2PACz/TTP-DPA-based devices showed an optimized performance of 19.1 and 37.0% under 1-sun and 3000 K LED (1000 lx) illuminations, respectively. These values represent improvements over those achieved by bare 2PACz-based devices, which attained efficiencies of 17.4 and 32.2%, respectively. These findings highlight the promising potential of TTs for the enhancement of the efficiencies of PSCs.

**KEYWORDS:** solar cell, perovskite, thiazolo[5,4-*d*]thiazole, indoor harvesting, hole-selective materials



## INTRODUCTION

Perovskite solar cells (PSCs), valued for their high power conversion efficiency (PCE), solution processability, and finely adjustable energy levels, have recently attracted considerable attention.<sup>1–4</sup> Their versatility is apparent in a variety of applications, from PSCs functioning optimally under one-sun illumination to indoor PSC (iPSCs) capable of harnessing energy from artificial lighting.<sup>5–8</sup> However, PSCs have yet to play an important role in the photovoltaic market, primarily due to certain limitations related to their relatively low stability in comparison to mature Si–PV devices. In order to improve the performance and stability of PSCs, numerous researchers have focused on interfacial engineering between carrier transport layers (CTLs) and perovskite layers.<sup>9–11</sup> Charge-selective materials and interfacial layers (IFLs) play crucial roles in the performance of PSCs. They not only accelerate charge extraction but also passivate defect states at interfaces.<sup>12,13</sup> Recent advancements have highlighted the effectiveness of specicized hole-selective layers (HSL) in

inverted-structured (p–i–n) PSCs.<sup>14</sup> Especially, molecules containing carbazole (Cz), phenothiazine (PTZ), and triphenylamine (TPA) moieties are preferred for their exceptional hole-extraction capabilities.<sup>15–18</sup> The desired HSL boasts robust thermal stability and superior mobility, along with suitable surface energies. Tailored adjustments are needed when positioning it beneath the perovskite layer to finely regulate perovskite growth, aiming for optimal performance.<sup>19–21</sup>

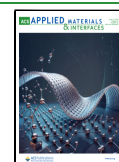
Thiazolothiazole is known for its planar and rigid structure with extended  $\pi$ -conjugation.<sup>22</sup> Derivatives with a conjugated thiazolo[5,4-*d*]thiazole (TT) moiety are used in organic field-

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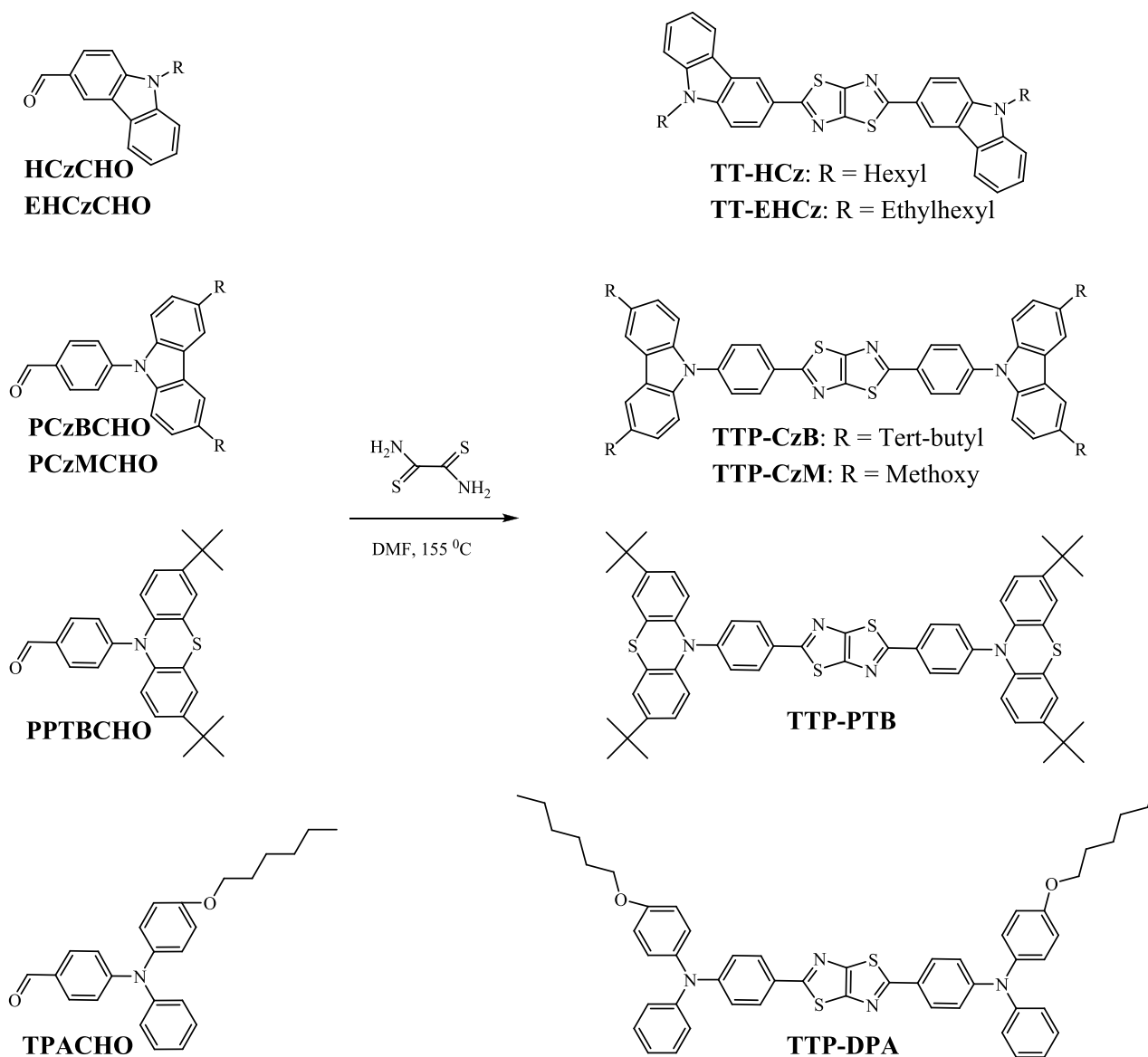
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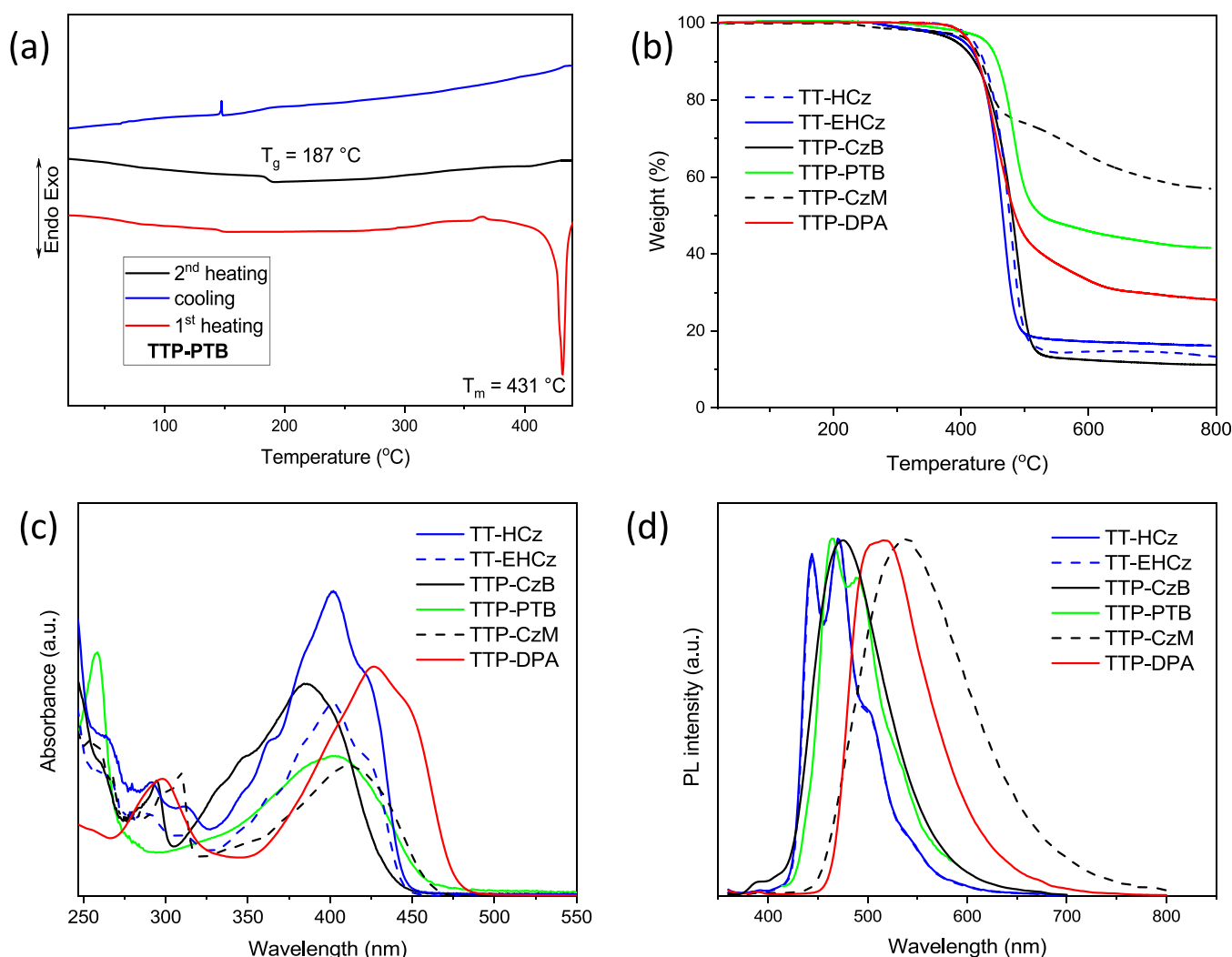
Scheme 1. Synthesis of TT Derivatives



effect transistors, dye-sensitized solar cells, and PSCs.<sup>23–25</sup> TT derivatives can be synthesized simply using a Pd-free synthetic route and affordable starting materials.<sup>25,26</sup> Compounds with Cz, PTZ, and TPA moieties are extensively employed for organic optoelectronic applications.<sup>27–31</sup> In this work, we designed and synthesized donor–acceptor–donor (D–A–D)-type hole-selective materials, featuring alkoxy- or alkyl-substituted Cz, PTZ, and TPA moieties as donor units and TT as the acceptor moiety. Our design strategy was based on the exploitation of the planar and rigid electron-deficient TT moiety, which can ensure efficient intermolecular  $\pi$ – $\pi$  overlap and high glass transition temperatures of the derivatives.<sup>22</sup> Electron-donating carbazolyl, phenothiazinyl, and triphenylamino groups were selected taking into account good charge-transporting properties of the derivatives containing these moieties.<sup>32–34</sup> Alkoxy groups were attached to the donor moieties taking into account their hydrogen bonding abilities, which result in the improvement of charge-transporting properties.<sup>35</sup> Meanwhile, attachment of *tert*-butyl groups allows to considerably increase glass transition temperatures ( $T_g$ ) and morphological as well as thermal stability of molecular

glasses.<sup>36</sup> The synthesized materials exhibit  $T_g$  of up to 187 °C and hole mobility ( $\mu_h$ ) of up to  $1.63 \times 10^{-3} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$  at an electric field of  $1.6 \times 10^5 \text{ V cm}^{-1}$ .

The interfaces between the perovskite and the HSL are responsible for most performance losses and interfacial instability in p–i–n PSCs.<sup>37,38</sup> Modification of the HSL/perovskite interface allows to improve energy level alignment, regulate perovskite crystallization, and reduce interfacial defects.<sup>39,40</sup> Efficient HSL design entails selecting building blocks with high  $T_g$  and  $\mu_h$  values, as well as suitable ionization potentials and surface energies.<sup>41</sup> Moreover, these HSLs can serve as defect passivation layers (i.e., IFL) to enhance the performance of PSCs using traditional HTLs such as nickel oxide ( $\text{NiO}_x$ ), [2-(9H-carbazol-9-yl)ethyl]phosphonic acid (2PACz), and [2(3,6-dimethoxy-9H-carbazol-9-yl)ethyl]-phosphonic acid (MeO-2PACz).<sup>42–44</sup> In this study, we introduce PSCs utilizing 2PACz and TT derivatives as materials for HSL. Additionally, we explore the impact of the layers of TTs as an interlayer to optimize the performance of 2PACz-based PSCs. X-ray diffraction, steady-state and time-resolved photoluminescence (PL) spectrometry, and scanning



**Figure 1.** DSC curves of compound TTP-PTB recorded at the heating rate of  $10\text{ }^{\circ}\text{C min}^{-1}$  in a nitrogen atmosphere (a). TGA curves of TT-based compounds recorded at the heating rate of  $20\text{ }^{\circ}\text{C min}^{-1}$  in a nitrogen atmosphere (b). Absorption (c) and PL (d) spectra of the dilute THF solutions of TT derivatives.

electron microscopy (SEM) were utilized to assess the phenomena of performance alteration. Transient photovoltage decays (TPV) and photocurrent decays (TPC) were analyzed alongside the results of charge carrier mobility measurements to evaluate carrier transport and extraction within the devices. Consequently, the optimized wide-bandgap  $\text{Cs}_{0.18}\text{FA}_{0.82}\text{Pb}(\text{I}_{0.8}\text{Br}_{0.2})_3$  PSC exhibited a PCE of 19.1% under one-sun ( $\text{AM 1.5G}$ ,  $100\text{ mW cm}^{-2}$ ) illumination, while indoor PSCs reached maximum PCEs of 37.0% under 3000 K LED illumination of 1000 lx. These findings disclose the potential of D–A–D-type molecule-based interface modification as a practical and efficient approach to enhance passivation and contact properties, thereby advancing the development of high-efficiency PSCs.

## RESULTS AND DISCUSSION

**Synthesis.** Donor-disubstituted TT derivatives were synthesized as shown in Scheme 1. TT-based compounds were obtained from the respective monoformyl derivatives and dithiooxamide in dry dimethylformamide at the reflux temperatures. The products were purified by column chromatography. All the synthesized compounds were identified by mass spectrometry,  $^1\text{H}$  NMR spectroscopy

(Figures S1–S4), and  $^{13}\text{C}$  NMR spectroscopy. The data were found to be in good agreement with the proposed structures.

**DSC AND TGA Studies.** The behavior under heating of the synthesized TT derivatives was studied by thermogravimetric analysis (TGA) and differential scanning calorimetry (DSC) under a nitrogen atmosphere. The TGA curves of the compounds are shown in Figure 1b. The results obtained are collected in Table 1. The TT derivatives demonstrated high thermal stability. Their 5% weight loss temperatures were found to be higher than  $390\text{ }^{\circ}\text{C}$ . They ranged from  $397$  to  $439\text{ }^{\circ}\text{C}$ . The substituents and their position did not significantly affect the temperature of the onset of weight loss. TGA curves of all the synthesized compounds showed nonvolatile residues at  $800\text{ }^{\circ}\text{C}$  with the percentage exceeding 14%. The considerable amounts of nonvolatile residues were also observed for the earlier reported derivatives of TT.<sup>25,45</sup> This observation shows that under heating, the samples of TT-based compounds are subjected to thermal decomposition but not to sublimation. The relatively high amounts of nonvolatile residues can be explained either by incomplete decomposition of the compounds or by cross-linking of the molecules. Most of the synthesized TT derivatives except TTP-CzM containing

Table 1. Thermal, Electrochemical, and Photoelectrical Characteristics of TT Derivatives

	TT-HCz	TT-EHCz	TTP-CzB	TTP-PTB	TTP-CzM	TTP-DPA
$T_{-5\%}^a$ [°C]	419	405	397	439	412	414
$T_g^b$ [°C]		46	130	187		46
$T_m^c$ [°C]	222	164	293	431	298	133
$T_{cr}^d$ [°C]	144	141	201		227	
$E_{ox}$ vs Fc [V] <sup>e</sup>	0.27	0.16	0.40	−0.21	−0.29	0.08
$E_{red}$ vs Fc [V]	−1.84	−1.63	−1.63	−2.29	−2.28	−2.47
IP <sub>CV</sub> [eV]	5.07	4.96	5.20	4.59	4.51	4.72
EA <sub>CV</sub> [eV]	3.23	3.40	3.57	2.30	2.23	2.25
$E_g^{opt}$	2.65	2.77	2.82	2.68	2.54	2.59
IP <sub>EP</sub> [eV]	5.06	4.93	5.67	5.47	5.35	5.01
$\mu_0$ [cm <sup>2</sup> /V·s]	$3.79 \times 10^{-8}$	$7.61 \times 10^{-8}$	$1.3 \times 10^{-4}$	$3.59 \times 10^{-7}$	$5.08 \times 10^{-5}$	$h: 6.16 \times 10^{-5}$ e: $1.34 \times 10^{-4}$
$\mu_h$ [cm <sup>2</sup> /V·s]	$4.33 \times 10^{-5f}$	$7.03 \times 10^{-5f}$	$3.11 \times 10^{-4f}$	$4.10 \times 10^{-4f}$	$1.63 \times 10^{-3g}$	$h: 3.97 \times 10^{-4g}$ e: $6.69 \times 10^{-4g}$
$\lambda_h$ [meV]	397.0	398.3	160.7	502.6	136.7	321.0

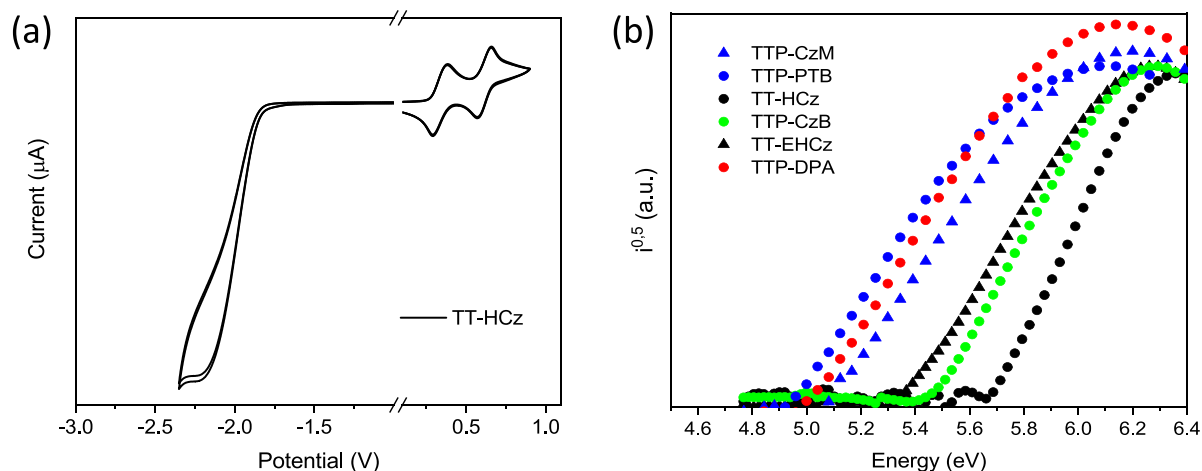
<sup>a</sup> $T_{-5\%}$ —5% mass loss temperature determined by TGA, heating rate 20 °C/min, N<sub>2</sub> atmosphere. <sup>b</sup> $T_g$ —glass transition temperature,  $T_m$ —melting point,  $T_{cr}$ —crystallization temperature, determined by DSC, scan rate 10 °C/min, N<sub>2</sub> atmosphere: second heating scan. <sup>c</sup> $T_g$ —glass transition temperature,  $T_m$ —melting point,  $T_{cr}$ —crystallization temperature, determined by DSC, scan rate 10 °C/min, N<sub>2</sub> atmosphere: first heating scan. <sup>d</sup> $T_g$ —glass transition temperature,  $T_m$ —melting point,  $T_{cr}$ —crystallization temperature, determined by DSC, scan rate 10 °C/min, N<sub>2</sub> atmosphere: cooling. <sup>e</sup> $E_{ox}$ ,  $E_{red}$ —onset potentials of oxidation and reduction, respectively. Ionization potentials (IP<sub>CV</sub>) and electron affinities (EA<sub>CV</sub>) estimated by CV according to the equations IP<sub>CV</sub> = 4.8 +  $E_{ox}$  vs Fc and EA<sub>CV</sub> = IP<sub>CV</sub> −  $E_{red}$  vs Fc. Ionization potential (IP<sub>ep</sub>) measured by PE spectrometry.  $\lambda_h$ —theoretically calculated values. <sup>f</sup>Hole drift mobility ( $\mu$ ) estimated by the TOF technique at electric field of  $4.9 \times 10^5$  V/cm. <sup>g</sup>Hole drift mobility ( $\mu$ ) estimated by the TOF technique at electric field of  $1.6 \times 10^5$  V/cm.

methoxy groups exhibited single-stage thermal degradations. TT-based compounds were isolated as crystalline substances after their synthesis (Figure S5, 1a). Compound TT-EHCz containing branched alkyl chains at the nitrogen atoms of Cz moieties showed glass transition at 46 °C in the second DSC heating scan. However, this sample was not morphologically stable and was recrystallized at 141 °C during the same DSC heating scan. A similar behavior was observed for compound TTP-CzB. TTP-CzB with *tert*-butyl-disubstituted Cz donor units formed molecular glass with high  $T_g$  of 130 °C. However, this sample was also not morphologically stable and showed crystallization signal in the same DSC heating scan. Compound TTP-CzM containing methoxy-disubstituted Cz donor moieties did not form molecular glass. Its sample showed an endothermic melting signal at 298 °C in the first DSC heating scan. In the cooling scan, the melted sample showed the exothermic crystallization signal at 227 °C. The following heating scan revealed only melting peaks again. The presence of double melting peaks at 282, 297 °C and 270, 298 °C in the DSC curves of TTP-CzB and TTP-CzM, respectively, shows that these compounds exhibited polymorphism. The DSC results showed that addition of the phenyl group to the molecule increased glass transition and melting temperatures. DSC measurements showed that compounds TTP-PTB and TTP-DPA formed relatively morphologically stable molecular glasses. The DSC measurements revealed melting peaks only in the first DSC heating scans of the compounds. Neither melting nor crystallization was observed either in the second or in the following DSC scans of the compounds. Compound TTP-PTB containing *tert*-butyl-disubstituted PTZ donor moieties showed very high  $T_g$  of 187 °C (Figure 1a), while compound TTP-DPA containing triphenylamino moieties showed glass transition at 46 °C.

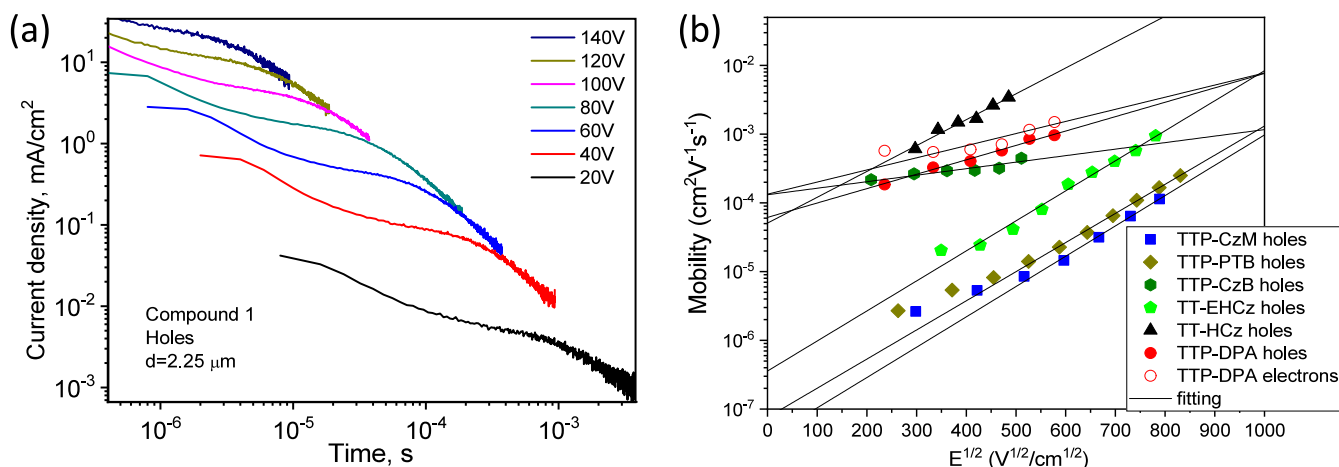
**Photophysical Properties.** UV–vis absorption spectra of the dilute solutions of TT derivatives are shown in Figure 1c. The synthesized compounds absorbed electromagnetic radiation in the range of up to 477 nm. The low energy band at 386 nm with the shoulder at ca. 406 nm was observed for

compound TTP-CzB. This band is very similar to the low energy band of TT and its derivatives.<sup>22</sup> This observation allows to suppose that the low energy band of compound TTP-CzB is mainly caused by locally excited (LE) states of thiazolo[5,4-*d*]thiazole. This is in agreement with the data of the theoretical calculations (see Theoretical Calculations), according to which only a weak intramolecular charge transfer (ICT) is observed for compound TTP-CzB. Replacement of a Cz fragment with the triphenylamino moiety in the TT derivatives as well as replacement of *tert*-butyl groups with methoxy groups led to the bathochromic shift of the lowest energy absorption bands by more than 20 nm. The shapes of the absorption bands of TT-based compounds are similar. The observed bathochromic shifts of the bands of compounds TTP-CzB, TTP-PTB, TTP-CzM, and TTP-DPA with respect to those of compounds TT-HCz and TT-EHCz are apparently caused by the enhanced conjugation due to the stronger donating abilities of the donor units. However, the effect of ICT between electron-accepting and electron-donating moieties on the shape and position of absorption spectra of compounds TTP-CzB, TTP-CzM, and TTP-DPA should also be taken into account. This is supported by the red shifts of emission spectra of the solutions of TT derivatives in the solvents with increasing polarities (Figure S6) and the data of theoretical calculations (see Theoretical Calculations). The normalized PL spectra of the dilute THF solutions of the TT derivatives are shown in Figure 1d. The PL spectrum of compound TTP-DPA containing triphenylamino groups exhibited red shifts by more than 40 nm compared to the spectra of the carbazoyl-containing compounds TT-HCz, TT-EHCz, and TTP-CzB and the PTZ-containing compound TTP-PTB. The PL spectrum of compound TTP-CzM containing methoxy-carbazoyl fragments was found to be the most red-shifted. This can be explained by the fact that the excitation of compound TTP-CzM is accompanied by the most efficient charge transfer (see Theoretical Calculations). The vibrational PL spectra of the solutions of TT-HCz, TT-EHCz, and TTP-PTB in THF can apparently be attributed to the local excitation of the molecules, while structureless PL





**Figure 2.** Cyclic voltammetry of compound TT-HCz recorded for 0.1 M Bu<sub>4</sub>NBF<sub>4</sub>/dichloromethane solution at a scan rate of 0.1 mV s<sup>-1</sup> (a) and photoelectron emission spectra of vacuum-deposited films of TT derivatives (b).



**Figure 3.** TOF signals for holes in the film of compound TT-HCz (a) and electric field dependences of hole mobilities (b) for the layers of TT derivatives and of electron mobilities for the layer of compound TTP-DPA.

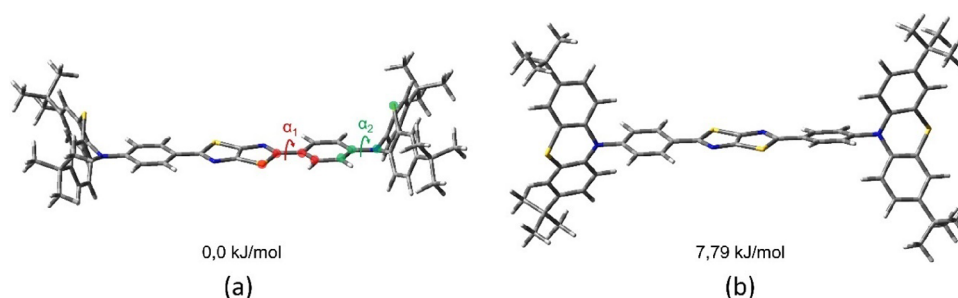
spectra of the solutions of TTP-CzB, TTP-CzM, and TTP-DPA in THF indicate ICT's nature. This is confirmed by the results of the theoretical calculations (see [Theoretical Calculations](#) for details). According to the calculations, the ICT nature of excited states of compounds TTP-CzB, TTP-CzM, and TTP-DPA can be explained by the fact that the 2,5-diphenylthiazolo[5,4-*d*]thiazole core and diphenylamine or Cz units are twisted. This effect was not observed in the case of compounds TT-HCz, TT-EHCz, and TTP-PTB, in which the 2,5-dicarbazol-3-yl-thiazolo[5,4-*d*]thiazole core or 2,5-diphenylthiazolo[5,4-*d*]thiazole unit is planar.

**Electrochemical and Photoelectrical Properties.** Cyclic voltammetry (CV) measurements were performed to study electrochemical properties of TT-based compounds. All the compounds showed reversible oxidation after repeated scans ([Figure S7, 2a](#)). The shapes of the CV curves of TT derivatives remained unchanged after several cycles. This observation shows formation of both stable radical cations and radical anions.

Ionization potential (IP<sub>CV</sub>) values were estimated from oxidation onset potentials against ferrocene ( $E_{ox}$  onset versus Fc). The IP<sub>CV</sub> values of the TT derivatives ranged from 4.51 to 5.20 eV ([Table 1](#)). The replacement of the Cz fragment by the PTZ moiety resulted in the decrease of the IP<sub>CV</sub> value by 0.61

eV (cf. IP<sub>CV</sub> of TTP-CzB and TTP-PTB). The replacement of *tert*-butyl groups by methoxy groups also resulted in the decrease of the IP<sub>CV</sub> value by 0.69 eV (cf. IP<sub>CV</sub> of TTP-CzB and TTP-CzM). The electron affinity (EA<sub>CV</sub>) values of TT compounds were found to fall in the range of 2.23–3.57 eV. The EA<sub>CV</sub> values were determined from the values of IP<sub>CV</sub> and reduction potential onset with respect to Fc. The ionization potentials (IP<sub>EP</sub>) of the solid layers of the compounds were established by the photoelectron emission method in air ([Figure 2b](#)). The values ranged from 4.93 to 5.67 eV ([Table 1](#)). Both the methods of estimation of ionization potentials demonstrated similar patterns. Higher IP<sub>EP</sub> values relative to the IP<sub>CV</sub> values were obtained since more energy was needed to knock out electrons from the compounds in the solid state than in solutions.<sup>46</sup>

**Charge-Transporting Properties.** Charge-transporting properties of the layers of the synthesized derivatives of TT were estimated by the time-of-flight (TOF) technique. TOF signals were recorded applying the positive and negative voltages at the ITO electrode, thus detecting transport of holes or electrons ([Figure 3a](#) and [Figure S8](#)). The hole transport was detected for all the studied compounds, while the electron transport was proved only for compound TTP-DPA. The charge transport in the layers of the TT derivative was found to



**Figure 4.** MN15/6-31+G(d) optimized in THF geometries of quasi-axial (a) and quasi-equatorial (b) conformers of compound **TTP-PTB** and their relative energies.

be dispersive. The experimental mobility values are in good agreement with the Poole–Frenkel relation  $\mu = \mu_0 e^{\beta E^{1/2}}$ , where  $\mu_0$  is the zero-field mobilities and  $\beta$  is the field dependence parameter. The values of  $\mu_0$  for the layers of TT-based compounds were obtained in the range from  $3.79 \times 10^{-8}$  to  $1.34 \times 10^{-4} \text{ cm}^2/\text{V}\cdot\text{s}$ . At a high electric field of  $1.6 \times 10^5 \text{ V/cm}$ , the highest hole mobility value of  $1.63 \times 10^{-3} \text{ cm}^2/\text{V}\cdot\text{s}$  was observed for compound **TTP-CzM** (Table 1). Both hole and electron transports were detected for the layer of **TTP-DPA** (Figure 3b). The other compounds exhibit a unipolar behavior, i.e., hole transport with the measurable mobility for holes only (Figure 3b). 9-N-Substituted Cz derivatives (**TTP-CzB**, **TTP-CzM**) showed considerably higher hole mobilities than the 3*H*-substituted Cz compounds (**TT-HCz**, **TT-EHCz**). The replacement of the PTZ fragment by the Cz fragment as well as the *tert*-butyl groups by methoxy groups resulted in the increase in the hole mobilities (Table 1). One of the key parameters defining the charge-transfer rate constant is charge reorganization energy ( $\lambda$ ), which is divided into the external ( $\lambda_{\text{ext}}$ ) and internal ( $\lambda_{\text{int}}$ ) parts.  $\lambda_{\text{ext}}$  is not considered in this work because of the complexity of the calculation. However, for compounds containing  $\pi$ -conjugated systems,  $\lambda_{\text{int}}$  considerably exceeds  $\lambda_{\text{ext}}$ .<sup>47,48</sup> Therefore,  $\lambda_{\text{int}}$  is a good index for estimation of charge drift mobility.  $\lambda_{\text{int}}$  for the hole transfer ( $\lambda_{\text{h}}$ ) was calculated according to eq 1<sup>48</sup> in the gas phase within density functional theory (see Theoretical Calculations below):

$$\lambda_{\text{h}} = E(\text{C}^+/\text{C}) - E(\text{C}^+/\text{C}^+) + E(\text{C}/\text{C}^+) - E(\text{C}/\text{C}) \quad (1)$$

where  $E(\text{C}^+/\text{C})$  represents the total energy of single-point  $\text{C}^+$  cations having the geometry of C neutral molecule and  $E(\text{C}^+/\text{C}^+)$  represents the total energy of  $\text{C}^+$  ions having optimized geometry.

The values of  $\lambda_{\text{h}}$  calculated for the studied compounds are presented in Table 1. The changes of  $\lambda_{\text{h}}$  values for the series of the compounds are consistent with the changes of the experimental  $\mu_{\text{h}}$  values, with the exception of compound **TTP-PTB** (Table 1). Thus, the lowest hole mobility was observed for compounds **TT-HCz** and **TT-EHCz**. These compounds are also characterized by the highest values of internal reorganization energies, which can be attributed by the larger and, therefore, more flexible quasi-planar  $\pi$ -conjugated system (TT with two Cz moieties vs TT with two phenyl moieties in the case of the other compounds, see Figure S9). Compounds **TTP-CzB** and **TTP-CzM** are characterized by the lowest values of internal reorganization energies, since they have two types of rigid  $\pi$ -conjugated systems, i.e., TTP and Cz. Due to the rigidity, the geometries of cations and neutral

molecules of **TTP-CzB** and **TTP-CzM** are similar. Therefore, the calculated  $\lambda_{\text{h}}$  values are small. The large value of  $\lambda_{\text{h}}$  observed for compound **TTP-PTB** is explained by the different geometries of neutral molecule and cation, caused by the increase in the angle between TTP and PTB moieties in cation. Presumably, such unfolding of the structure, in the case when the molecules form layers, is difficult. Therefore, the calculated value of the internal reorganization energy for compound **TTP-PTB** does not agree with the experimental  $\mu_{\text{h}}$ .

**Theoretical Calculations.** The geometry and electronic structures of the compounds in ground and excited states were calculated within density functional theory (DFT) using the MN15<sup>49</sup> functional with the 6-31+G(d) basis set in solution of THF. Solvation effects were considered using the SMD model<sup>50</sup> in terms of the linear response scheme.<sup>51</sup> For the calculations of the absorption spectra, the geometries of the ground states (S0) of the compounds were fully optimized in solution with subsequent calculation of the spectra within the TD-DFT approach. The vibration frequencies were calculated for all the optimized structures to confirm that they correspond to the minima of the potential energy surfaces. For the calculations of the PL spectra, the geometry of the first singlet excited state (S1) was fully optimized in solution within TD-DFT. All the optimized structures in the ground (S0) and excited (S1) states had a point group of  $\text{C}_2$ . In the case of compound **TTP-PTB**, containing PTZ moieties, we have considered both quasi-axial and quasi-equatorial conformers (Figure 4). The results of our calculations show that the quasi-axial conformer has almost 8 kJ/mol lower total energy value than the quasi-equatorial one in the ground state (Figure 4) and almost 9 kJ/mol lower energy in the first excited state. This corresponds to the molar fraction of the quasi-equatorial conformer of less than 5% in the equilibrium mixture at a temperature of 298 K. Moreover, the value calculated for the quasi-equatorial conformer of the absorption maximum ( $\lambda_{\text{ABS}}(\text{calc.}) = 367 \text{ nm}$ ) is underestimated compared to the experimental value ( $\lambda_{\text{ABS}}(\text{exp.}) = 403 \text{ nm}$ ). The calculated values of IHOMO and LUMO energies ( $-6.05$  and  $-1.77 \text{ eV}$ ) do not match the experimentally determined changes in  $\text{IP}_{\text{CV}}$  and  $\text{EA}_{\text{CV}}$  in a row of considered compounds. Therefore, further in this paper, the results of calculations will be analyzed only for the quasi-axial conformer of compound **TTP-PTB**. All the calculations were carried out using the Gaussian 16 program.<sup>52</sup> The analysis of electron density was performed using Multiwfn software.<sup>53</sup>

The calculated wavelengths corresponding to the first absorption maxima ( $\lambda_{\text{ABS}}^1$ ), wavelengths corresponding to the transition  $\text{S1} \rightarrow \text{S0}$  in the PL spectra ( $\lambda_{\text{PL}}$ ), dihedral angles between TT and Cz or phenyl units ( $\alpha_1$ , see Figure 4) and

**Table 2.** MN15/6-31+G(d) Calculated for TT-Based Compounds in THF, the Wavelengths Corresponding to the First Absorption Maxima ( $\lambda_{\text{ABS}}^1$ ), Wavelengths Corresponding to Maxima of PL Spectra ( $\lambda_{\text{PL}}$ ), Dihedral Angles between Donor and Acceptor Moieties ( $\alpha$ ), Values of the Largest Coefficients in the CI Expansion ( $c$ ), Oscillator Strengths ( $f$ ), Overlaps between Functions  $C_+$  and  $C_-$  ( $S_{+-}$ -Index) and Energy Gap between the Singlet and Triplet States ( $\Delta E_{\text{S-T}}$ )

parameter	TT-HCz	TT-EHCz	TTP-CzB	TTP-PTB	TTP-CzM	TTP-DPA
$\lambda_{\text{ABS}}^1$ [nm]	398 (402) <sup>a</sup>	399 (401)	407 (386)	407 (403)	421 (413)	444 (427)
$\alpha_1$ and $\alpha_2$ [°]	13	11	5 and 52	0 and 90	2 and 52	6 and 30
$c(\text{HOMO} \rightarrow \text{LUMO})$	0.677	0.678	0.624	0.681	0.622	0.662
$f$	1.995	2.022	1.937	2.109	1.812	2.244
$S_{+-}$ -index	0.930	0.952	0.922	0.961	0.907	0.928
$\Delta E_{\text{S-T}}$ [eV] <sup>b</sup>	0.765	0.765	0.757	0.797	0.684	0.649
$\lambda_{\text{PL}}$ [nm]	507 (444, 470)	508 (444, 470)	512 (476)	523 (464, 488)	520 (536)	550 (516)
$\alpha_1$ and $\alpha_2$ [°]	0	1	0 and 46	1 and 90	1 and 46	0 and 34
$c(\text{HOMO} \rightarrow \text{LUMO})$	0.693	0.693	0.673	0.691	0.657	0.681

<sup>a</sup>The experimental values of  $\lambda_{\text{ABS}}^1$  and  $\lambda_{\text{PL}}$  are given in brackets. <sup>b</sup>Energy gap between the singlet and triplet states ( $\Delta E_{\text{S-T}}$ ) was calculated as energy difference between S1 and T1 excited states having the ground state geometry in THF.

dihedral angles between phenyl and Cz, PTZ, or diphenylamine units ( $\alpha_2$ , see Figure 4), values of the largest coefficients in the CI expansion ( $c$ ), oscillator strengths ( $f$ ), energy gap between the singlet and triplet states ( $\Delta E_{\text{S-T}}$ ) and overlaps between functions  $C_+$  and  $C_-$  ( $S_{+-}$ -indexes<sup>53</sup>) are given in Table 2. The calculated absorption spectra of considered compounds as well as the shapes and energies of HOMO and LUMO are presented in Figure 5. The calculated plots of  $\Delta\rho$  S1–S0 are given in Figure 6. The shapes of natural transition orbitals (NTOs) for S1  $\rightarrow$  S0 transitions are presented in Figures S10 and S11 of the Supporting Information.

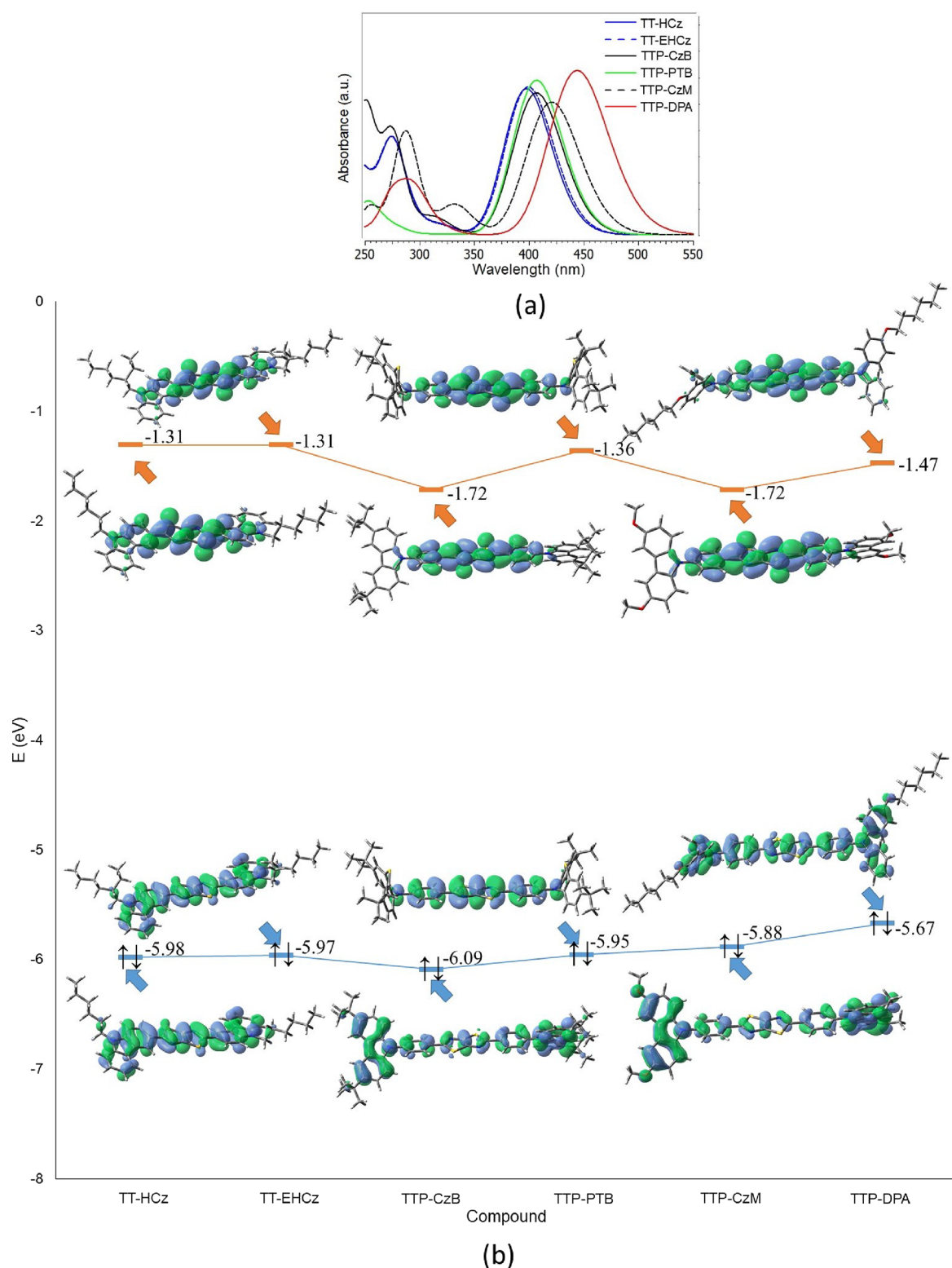
The calculated spectra within MN15/6-31+G(d) method absorption of TT-based compounds (Figure 5) are in excellent agreement with the experimental ones (Figure 1c). The shapes of the absorption bands of synthesized TT compounds are similar. The lowest energy band maxima lie in the range of 390–450 nm (Table 2), which is in good agreement with the experimental wavelengths of absorption maxima. The largest difference between the calculated and experimental values of  $\lambda_{\text{ABS}}^1$  is observed for compound TTP-CzB, but it is only of 21 nm. Compound TTP-CzB is characterized by the broad first absorption band (see Figure 1c).

According to the calculations for all the studied compounds, the first absorption peak in the absorption spectrum can be attributed to HOMO  $\rightarrow$  LUMO transition (see the values of largest coefficients in the CI expansion for S0  $\rightarrow$  S1 excitation in Table 2). The large values of the calculated  $f$ ,  $S_{+-}$ -indexes and  $\Delta E_{\text{S-T}}$  values show that the first maxima in the absorption spectra of all considered compounds correspond to the mainly local excitation (LE) with the strongest overlap between of S0 and S1 electron densities for TT-EHCz and TTP-PTB (see the values of  $S_{+-}$ -indexes in Table 2). Nevertheless, for compounds TTP-CzB and TTP-DPA and especially for TTP-CzM, the calculated values of  $S_{+-}$ -indexes are lower than those estimated for TT-HCz, TT-EHCz, and TTP-PTB, which may indicate a weak ICT nature of S0  $\rightarrow$  S1 transition. Indeed, in the case of compounds TTP-CzB and TTP-CzM, the significant part of electron density of HOMO is located on Cz moieties (Figure 5), which are turned by 52° with respect to phenyl rings (Table 2). The electron density of LUMO of the compounds is almost completely localized on a planar 2,5-diphenylthiazolo[5,4-*d*]thiazole unit (Figure 5). Therefore, the mixed LE and ICT transition occurs in the case of compounds TTP-CzB and TTP-CzM. The same situation is observed for compound TTP-DPA. As it can be seen from Figure 5, the

part of electron density of HOMO is located on the diphenylamino moiety, which is turned by 30° relative to the phenyl ring. Meanwhile, the electron density of LUMO is localized on the planar 2,5-diphenylthiazolo[5,4-*d*]thiazole moiety. In the case of compounds TT-HCz and TT-EHCz, the first band in the absorption spectra corresponds to the local excitation of the molecules (see the shapes of HOMOs and LUMOs of these compounds in Figure 5) since the TT moiety and Cz units are in the same plane. In compound TTP-PTB, the PTZ moieties are turned by 90° relative to the 2,5-diphenylthiazolo[5,4-*d*]thiazole unit. Therefore, the PTZ moieties do not contribute to either HOMO or LUMO (Figure 5). The ICT found for compounds TTP-CzB, TTP-CzM, and TTP-DPA can be seen more clearly in Figure 6. For these structures, especially in the case of compound TTP-CzM containing donor methoxy groups, the blue region of electron density is concentrated on the outermost moieties (Cz or diphenylamine).

The changes of HOMO energies for the series of TT-based compounds (Figure 5) are consistent with the changes of the experimental  $\text{IP}_{\text{CV}}$  values (Table 1). Thus, compounds TTP-PTB, TTP-CzM, and TTP-DPA have slightly higher HOMO energies and lower  $\text{IP}_{\text{CV}}$  values with respect to those of compounds TT-HCz, TT-EHCz, and TTP-CzB. Compound TTP-CzB is characterized by the lowest HOMO and the highest  $\text{IP}_{\text{CV}}$  values. It should be noted that the changes in HOMO energies in the series of considered compounds are not as pronounced as the changes in the  $\text{IP}_{\text{CV}}$ , and the absolute values of the HOMO energies do not coincide with the values of the  $\text{IP}_{\text{CV}}$ . This is not surprising, since the ionization leads to the change of the distribution of the total electron density in a molecule. The changes of LUMO energies for the series of TT-based compounds (Figure 5) are less consistent with the changes of  $\text{EA}_{\text{CV}}$  values (Table 1). This observation is explained by the difficulties of accurately calculating the energies of virtual orbitals within DFT.

The calculated wavelengths of maxima of the PL spectra of TT derivatives are in worse agreement with the experimental values than those of the absorption spectra (Table 2). This observation is explained both by the difficulty of optimization of the geometry for the excited state and by the higher error when considering the influence of the solvent in the framework of the LR scheme. The geometries of the compounds in the S1 excited state and the nature of S1  $\rightarrow$  S0 transitions are similar to those observed for the ground state. The analysis of MN15/



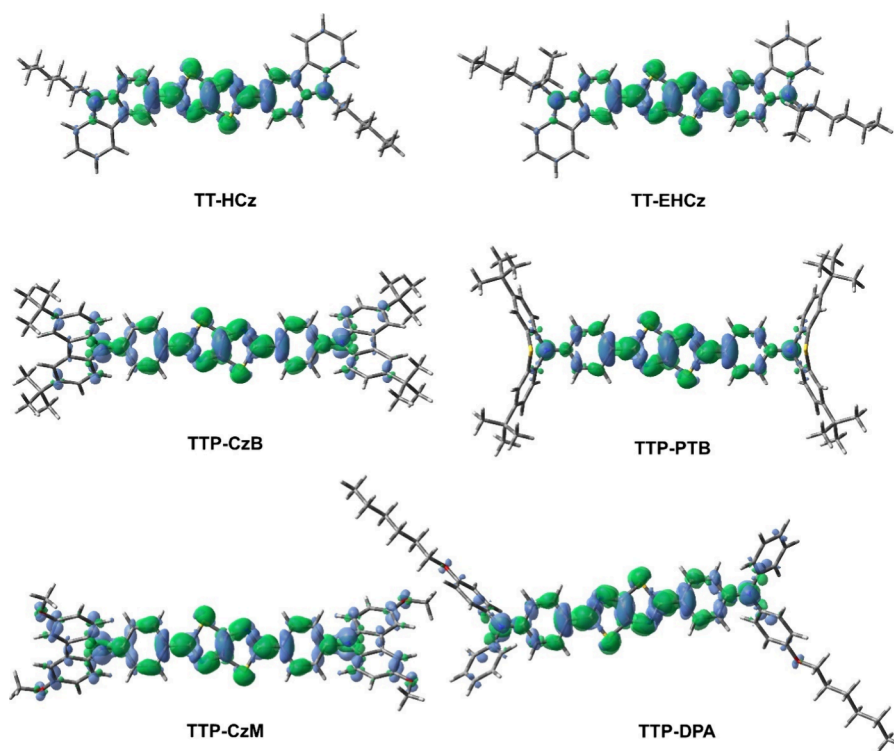
**Figure 5.** MN15/6-31+G(d) calculated absorption spectra (a). Shapes and energies of HOMO and LUMO (b) of TT-based compounds in THF.

6-31+G(d) calculated plots of  $S_1 \rightarrow S_0$  NTOs shows that the PL spectra of compounds **TT-HCz**, **TT-EHCz**, and **TTP-PTB** can be attributed to the local excitation of the planar 2,5-dicarbazol-3-yl-thiazolo[5,4-*d*]thiazole moiety or 2,5-diphenylthiazolo[5,4-*d*]thiazole unit (Figure S10). PL spectra of compounds **TTP-CzB**, **TTP-CzM**, and **TTP-DPA** the PL correspond to the mixed LE-ICT transitions, in which the

charge transfer from twisted Cz or diphenylamino units to the 2,5-diphenylthiazolo[5,4-*d*]thiazole moiety occurs (Figure S11). The strongest ICT is observed for compound **TTP-CzM**. This explains that the experimental PL spectrum of the compound **TTP-CzM** is the most red-shifted.

**Application in Perovskite Photovoltaics.** To explore the potential of TT-based compounds for hole-selective

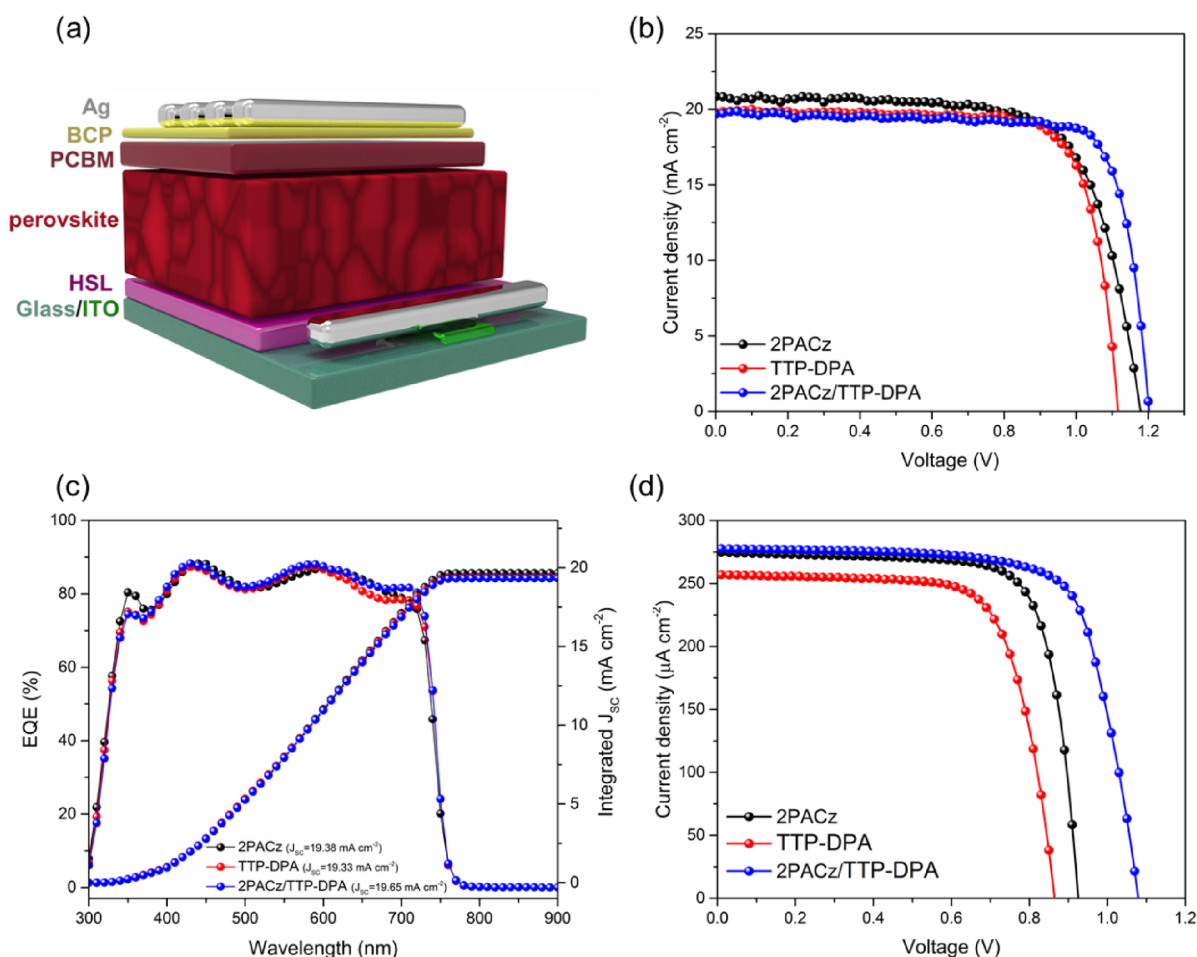




**Figure 6.** MN15/6-31+G(d) calculated for TT-based compounds in THF plots of  $\Delta\rho$  S1–S0. Green (blue) regions indicate increase (decrease) in  $\rho$  upon electronic transition.

contacts, we assessed their impact on the performance of PSCs with wide band gaps (WBGs) of 1.70 ( $\text{Cs}_{0.18}\text{FA}_{0.82}\text{Pb}(\text{I}_{0.8}\text{Br}_{0.2})_3$ ) and 1.77 ( $\text{Cs}_{0.18}\text{FA}_{0.82}\text{Pb}(\text{I}_{0.6}\text{Br}_{0.4})_3$ ) eV using an inverted p–i–n device architecture: ITO/HSLs/perovskites/ $\text{PC}_{61}\text{BM}/\text{BCP}/\text{Ag}$  (refer to Figure 7a). We prepared the TT-based compound HSLs on top of ITO using a concentration of 3.0 mg/mL. Further increasing the concentration of the hole-selective materials resulted in poor coverage of the perovskite layer. Detailed fabrication conditions are provided in Experimental Section. Table S2 presents the characteristics of HSL-based  $\text{Cs}_{0.18}\text{FA}_{0.82}\text{Pb}(\text{I}_{0.8}\text{Br}_{0.2})_3$  and  $\text{Cs}_{0.18}\text{FA}_{0.82}\text{Pb}(\text{I}_{0.6}\text{Br}_{0.4})_3$  PSCs under one-sun illumination (AM 1.5 G 100  $\text{mW cm}^{-2}$ ). Additionally, we prepared HSL-free devices for the comparison. As depicted in Table S2, compound **TTP-DPA** exhibited the best performance under the testing conditions. Notably, the performance of these HSL-containing PSCs is influenced not only by the energy levels, charge mobility, and optoelectronic properties of these HSL compounds but also by factors such as their solubility, film formation, and quality of the films, which determine their suitability for PSCs. Considering the best performance of the **TTP-DPA** device, we focused solely on the study of the  $\text{Cs}_{0.18}\text{FA}_{0.82}\text{Pb}(\text{I}_{0.8}\text{Br}_{0.2})_3$  PSCs fabricated using compound **TTP-DPA**. We investigated the effect of the concentration of the solution of **TTP-DPA** on the thickness and quality of the HSL and, consequently, the overall performance of the PSCs. The PCEs of PSCs prepared with the concentrations of **TTP-DPA** of 0.5, 1.0, 1.5, and 3.0 mg/mL were measured to be 7.6, 11.4, 15.1, and 17.1% (Table S2), respectively. The observed trend indicates that an increased thickness of the layer of compound **TTP-DPA** leads to the notable improvement the device performance. The best performance was achieved using the solution with the concentration of 3 mg/mL, with the short-circuit current density ( $J_{\text{SC}}$ ) of 19.8  $\text{mA cm}^{-2}$ , an open circuit voltage ( $V_{\text{OC}}$ )

of 1.09 V, and a fill factor (FF) of 79.3%. To compare the performance of the device with compound **TTP-DPA**, two different PSCs with HSLs of 2PACz (control) and 2PACz/**TTP-DPA** were fabricated and evaluated (Figure 7b and Table S3). The control device with HSL of 2PACz control devices exhibited a PCE of  $17.0 \pm 0.5\%$  with a  $J_{\text{SC}}$  of  $19.4 \pm 1.1 \text{ mA/cm}^2$ , a  $V_{\text{OC}}$  of  $1.18 \pm 0.02 \text{ V}$ , and an FF of  $74.5 \pm 2.4\%$ . These devices exhibited a performance similar to that reported for PSCs having a similar device structure and perovskite composition.<sup>54</sup> The application of 2PACz continues to face challenges due to suboptimal reproducibility caused by insufficient surface coverage and the existence of voids within the perovskite layer at the interface.<sup>55</sup> The layer of compound **TTP-DPA** shows great potential to serve as an efficient HSL, compared with that of 2PACz in terms of PCE and FF. This may be attributed to the efficient hole extraction and the decreased number of defect states at the interface. The lower  $V_{\text{OC}}$  of the compound **TTP-DPA**-containing device could be due to a mismatch of energetic alignment. This issue was then addressed by combining 2PACz and **TTP-DPA** to form a bilayer HSL. The device with an HSL of 2PACz/**TTP-DPA** exhibited a PCE of  $18.4 \pm 0.7\%$  with a  $J_{\text{SC}}$  of  $19.6 \pm 0.2 \text{ mA/cm}^2$ , a  $V_{\text{OC}}$  of  $1.18 \pm 0.02 \text{ V}$ , and an FF of  $79.2 \pm 1.5\%$ , outperforming the control device. Figure 7c displays the plots of the external quantum efficiency (EQE) and the integrated  $J_{\text{SC}}$  versus wavelength recorded for the devices, showing the negligible mismatches between EQE response and the  $J_{\text{SC}}$  obtained from  $J$ – $V$  measurement. In addition, we utilized an indoor lighting simulator comprising a 3000 K LED array to evaluate the performance of iPSCs. The corresponding emission spectrum, depicted in Figure S13, aligns with the light harvesting of perovskite  $\text{Cs}_{0.18}\text{FA}_{0.82}\text{Pb}(\text{I}_{0.8}\text{Br}_{0.2})_3$ . Under illumination from a 3000 K LED source with the intensity of 1000 lx, the average PCE of the optimized device (2PACz/



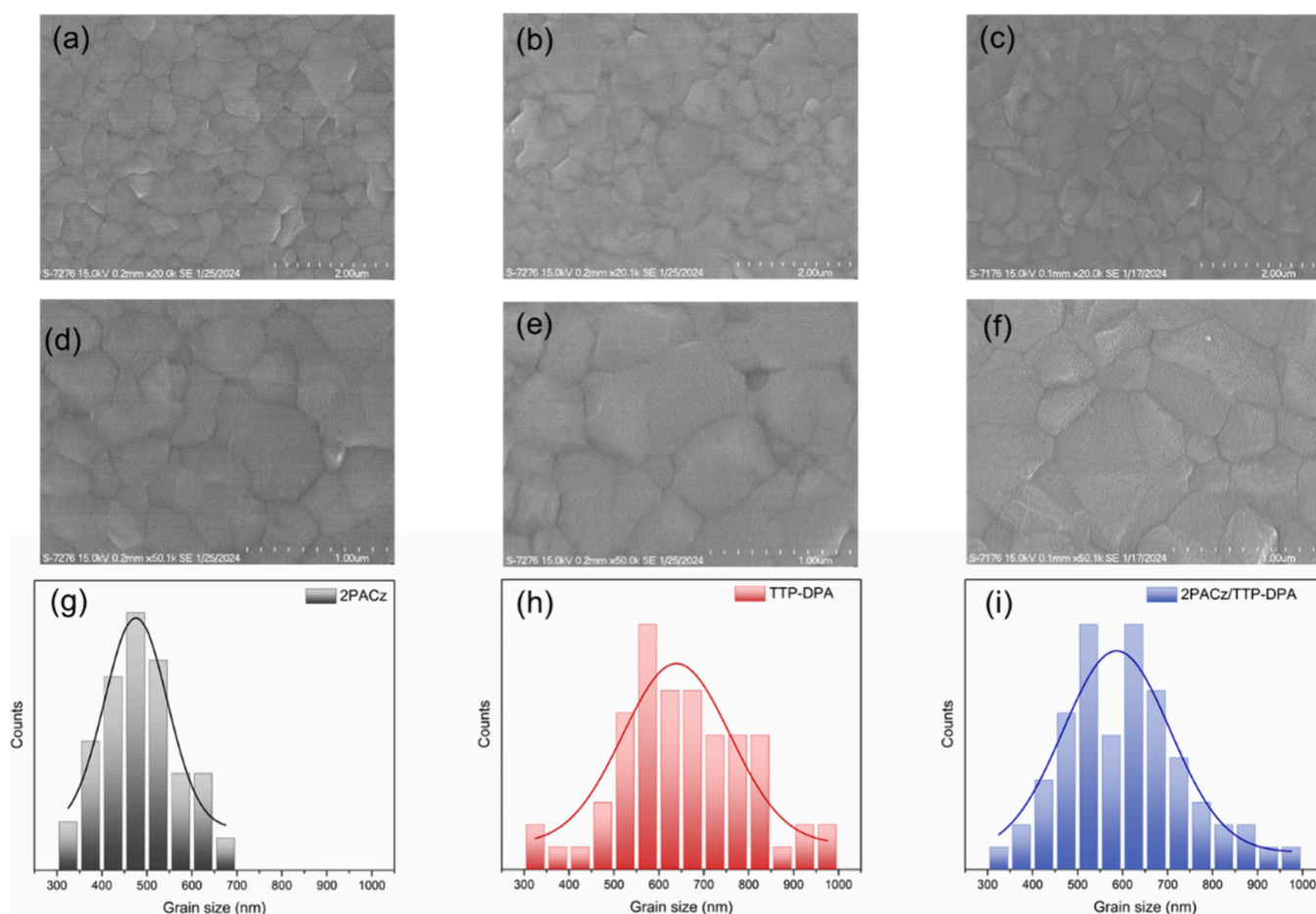
**Figure 7.** Device architecture (a);  $J$ – $V$  curves from the best PCE results under one-sun illumination (b); EQE characteristic (c) and  $J$ – $V$  curves from the best PCE results under 3000 K LED illumination (d).

TTP-DPA-based) achieved  $33.7 \pm 2.2\%$ , accompanied by a  $J_{SC}$  of  $262.1 \pm 11.4 \mu\text{A cm}^{-2}$ , a  $V_{OC}$  of  $1.00 \pm 0.05 \text{ V}$ , and an FF of  $76.3 \pm 2.5\%$ , with the best PCE reaching  $37.0\%$  (Figure 7d and Table S3).

Taking into account the substantial influence of the surface properties on perovskite crystallization, contact angle (CA) analyses were carried out employing water and diiodomethane (DIM) as probe fluids. The results obtained are shown in Figure S14 and in Table S4. The average water contact angles ( $CA_{\text{water}}$ ) of 2PACz, TTP-DPA, and 2PACz/TTP-DPA were found to be of  $53.1$ ,  $87.9$ , and  $75.2^\circ$ , respectively, suggesting the increase in hydrophobicity due to the incorporation of compound TTP-DPA. Additionally, the surface tension of polar ( $\gamma_p$ ) and dispersive ( $\gamma_d$ ) components along with total surface energy ( $\gamma_{\text{total}}$ ) was calculated from  $CA_{\text{water}}$  and  $CA_{\text{DIM}}$  according to the Wu model.<sup>56</sup> As listed in Table S4, the calculated  $\gamma_{\text{total}}$  of 2PACz, TTP-DPA, and 2PACz/TTP-DPA are of  $66.9$ ,  $52.4$ , and  $58.2 \text{ mN m}^{-1}$ , respectively, indicating that compound TTP-DPA can mitigate the barrier of high surface energy, significantly influencing perovskite formation.<sup>57</sup> The crystallization of perovskite was examined using SEM and X-ray diffraction (XRD). All perovskite films exhibited dense and pinhole-free structures (Figure 8a–f) and displayed typical pseudocubic diffraction peaks (Figure S15a). The enlargement of grain size in perovskites deposited on the layers of TTP-DPA (Figure 8g–i) indicates the capability of TTP-DPA to passivate defects, thereby promoting perovskite growth. As

shown in Figure S15a, the diffraction angles ( $2\theta$ ) of  $14.1$ ,  $20.1$ ,  $24.6$ , and  $28.5^\circ$  correspond to the  $(1\ 0\ 0)$ ,  $(1\ 1\ 0)$ ,  $(1\ 1\ 1)$ , and  $(2\ 0\ 0)$  crystal planes of the perovskite, respectively.<sup>58,59</sup> The distinctive diffraction peak at  $12.7^\circ$  represents residual  $\text{PbI}_2$ . However, in the TTP-DPA-contacting perovskite film, there is no evident diffraction peak at  $12.7^\circ$ , indicating that the TTP-DPA surface fosters perovskite growth, possibly due to its appropriate surface energy in suppressing perovskite grain boundary defects.<sup>60</sup>

We conducted PL measurements using the sample structure of ITO/HSL/perovskite to investigate the influence of compound TTP-DPA on the optoelectronic properties. As illustrated in Figure S15b, the trend of PL intensity is  $2\text{PACz}/\text{TTP-DPA} > 2\text{PACz} > \text{TTP-DPA}$ . This observation indicates the pronounced nonradiative recombination at the interface between ITO/TTP-DPA and perovskite.<sup>55</sup> When perovskite was deposited on ITO/2PACz and ITO/2PACz/TTP-DPA substrates, they exhibited higher PL intensity, implying that 2PACz could significantly alter the energy alignments between ITO and perovskite (also see Table S2). The carrier extraction was studied by time-corrected single photo counting (TCSPC) measurements, as depicted in Figure S15c. TTP-DPA-contacting perovskite films exhibited the shorter decay profiles, while 2PACz-contacting perovskite films exhibited the longer carrier lifetime. We attributed this mainly to the suppressed nonradiative recombination at the 2PACz/perovskite interface, which agrees with the stronger PL intensity. Additionally, the



**Figure 8.** SEM ( $\times 20k$ : a–c) and SEM ( $\times 50k$ : d–f) images of perovskite deposited on 2PACz (a, d), TTP-DPA (b, e), and 2PACz/ TTP-DPA (c, f). Grain size distribution from SEM images (g–i).

ITO/2PACz/TTP-DPA/perovskite sample showed the highest PL intensity and a trade-off carrier lifetime, which can be attributed to the presence of TTP-DPA, improving the perovskite growth, as evidenced by SEM and XRD results.<sup>40,61,62</sup>

We then conducted TPV and TPC measurements to delve deeper into carrier recombination and extraction dynamics in the devices. TPV analysis aids in assessing the photovoltaic efficiency by evaluating the separation of light-generated charge carriers. The TTP-DPA-containing device showed a shorter photovoltage decay lifetime of 2.54  $\mu\text{s}$  (Figure S16a). The 2PACz- and 2PACz/TTP-DPA-containing devices showed lifetimes of 4.12 and 3.93  $\mu\text{s}$ , respectively. This indicates a slight mismatch in energy level alignment at the interface, supporting our hypothesis regarding the observed low  $V_{\text{OC}}$  in  $J$ – $V$  measurements. We employed TPC analysis to investigate the collection rate of light-generated charge carriers in optoelectronic devices. The TTP-DPA-derived device showed a marginally faster TPC decay lifetime of 0.66  $\mu\text{s}$  (Figure S16b) compared to that of the 2PACz device (0.69  $\mu\text{s}$ ), suggesting that TTP-DPA performs comparably to the well-established HSL of 2PACz. Additionally, we observed further improvement in carrier extraction when employing the HSL of 2PACz/TTP-DPA in the devices. To estimate the average mobility of free charges within devices, the charge extraction of photogenerated charge carriers by linearly increasing voltage (photo-CELIV) was performed. The charge mobility ( $\mu$ ) can be calculated from the equation

$$\mu = \frac{2d^2}{3A\tau_{\text{max}}^2} \times \frac{1}{\left(1 + 0.36 \frac{\Delta J}{J_{(0)}}\right)}, \text{ where } d \text{ is the thickness of the active}$$

layer,  $A$  is the ramp rate of the applied voltage pulse (using 100  $\text{V ms}^{-1}$  in this work), and  $\tau_{\text{max}}$  is the time when the current density reaches the maximum value. The factor  $(1 + 0.36 \cdot \Delta J / J_{(0)})$  is an empirical correction for the redistribution of the electric field, where  $J_{(0)}$  is the displacement current offset and  $\Delta J$  is the current overshoot. From the curves shown in Figure S16c, a slightly shorter  $\tau_{\text{max}}$  was obtained for the devices incorporating TTP-DPA, giving the higher  $\mu$  of  $1.35 \times 10^{-3}$  and  $1.25 \times 10^{-3} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$  for PSCs containing the layers of TTP-DPA and 2PACz/TTP-DPA, respectively. In contrast, the control device with HSL of 2PACz showed  $\mu$  of  $1.18 \times 10^{-3} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ . The passivation effect becomes increasingly significant in environments with lower light intensity. Under 1 sun illumination, traps within the perovskite may be filled with many photocarriers. However, in dim light conditions, characterized by low photocarrier density, traps within the perovskite could significantly impact the performance of the PSC. The effect of TTP-DPA on perovskite is dual. On the one hand, it facilitates better perovskite growth; on the other hand, it enhances carrier extraction. Both functions contribute to collecting more photogenerated carriers under low-lighting conditions, consequently improving the  $V_{\text{OC}}$  value.

To gain further insight into the potential of TTP-DPA forming highly thermally stable HSL, we conducted the thermal stability tests of the devices without encapsulation



using a hot plate at 80 °C. As shown in Figure S16d, after more than 30 h of the thermal treatment, the PCE of the device containing HSL of TTP-DPA retained ca. 80% of its initial PCE. In contrast, the PCE of the devices employing 2PACz (i.e., 2PACz- and 2PACz/TTP-DPA-based) experienced a rapid decline over the same duration. This remarkable thermal stability underscores the potential of TT derivatives for HSL of the next-generation photovoltaics.<sup>63–65</sup>

## EXPERIMENTAL SECTION

**Materials.** Dithiooxamide was purchased from “Aldrich” and used as received. The solvents were purified and dried using standard procedures.<sup>66</sup> [2-(9H-Carbazol-9-yl)ethyl]phosphonic acid (2PACz, >98%, TCI), cesium chloride (CsCl, 99.9%, ultra dry, Alfa Aesar), formamidinium iodide (FAI, >99.99%, Greatcell Solar), lead iodide (PbI<sub>2</sub>, 99.9985%, Alfa Aesar), lead bromide (PbBr<sub>2</sub>, 99.99%, Alfa Aesar), ethanol (anhydrous, ECHO), bathocuproine (BCP, Aldrich), dimethyl sulfoxide (DMSO, Sigma-Aldrich), *N,N*-dimethylformamide (DMF, Acros Organics), phenethylammonium iodide (PEAI, Greatcell Solar), and PC<sub>61</sub>BM (Nano-C) were used as received. The starting and some target compounds were synthesized by the reported procedures: 9-hexyl-9H-carbazole-3-carbaldehyde,<sup>67</sup> 9-(2-ethylhexyl)-9H-carbazole, 9-(2-ethylhexyl)-9H-carbazole-3-carbaldehyde (EHCz-CHO),<sup>68</sup> 4-(3,6-ditert-butyl-9H-carbazol-9-yl)benzaldehyde (PCzBCHO),<sup>69</sup> 4-(3,7-ditert-butyl-10H-phenothiazin-10-yl)-benzaldehyde (PPTBCHO),<sup>70</sup> 4-(3,6-dimethoxy-9H-carbazol-9-yl)-benzaldehyde (PCzMCHO),<sup>71</sup> 2,5-bis(9-hexylcarbazol-3-yl)thiazolo[5,4-*d*]thiazole (TT-HCz), and 4,4′-(thiazolo[5,4-*d*]thiazole-2,5-diyl)bis(*N*-(4-(hexyloxy)phenyl)-*N*-phenylaniline) (TTP-DPA).<sup>72</sup> 2,5-Bis(9-(2-ethylhexyl)carbazol-3-yl)thiazolo[5,4-*d*]thiazole (TT-EHCz). 9-Hexylcarbazol-3-carbaldehyde 0.75 g (2.88 mmol) and dithiooxamide 0.175 g (1.44 mmol) were dissolved in 5 mL of DMF. The reaction was carried out at 160 °C for 8 h. After cooling to room temperature, the mixture was poured into distilled water. The yellow precipitate was filtered off and washed with water. The crude product was purified by column chromatography (*n*-hexane/ethyl acetate vol. ratio 10:1) and recrystallized from eluent to obtain yellow crystals of TT-EHCz (0.26 g, 26%), mp 152–154 °C.

<sup>1</sup>H NMR (400 MHz, CDCl<sub>3</sub>) δ 8.75 (s, 2H), 8.21 (d, *J* = 7.7 Hz, 2H), 8.11 (d, *J* = 8.6 Hz, 2H), 7.51 (t, *J* = 7.6 Hz, 2H), 7.44 (t, *J* = 9.2 Hz, 2H), 7.30 (t, *J* = 7.4 Hz, 2H), 4.20 (d, *J* = 7.3 Hz, 4H), 2.06–2.12 (m, 2H), 1.26–1.43 (m, 16H), 0.94 (t, *J* = 7.4 Hz, 6H), 0.87 (t, *J* = 7.1 Hz, 6H).

<sup>13</sup>C NMR (101 MHz, CDCl<sub>3</sub>) δ 167.76, 157.82, 142.28, 141.53, 141.49, 134.18, 126.36, 124.83, 125.31, 124.34, 123.32, 122.85, 120.78, 119.65, 118.65, 109.43, 55.51, 47.64, 39.43, 31.02, 28.81, 24.42, 23.05, 14.05, 10.93.

FTIR (cm<sup>−1</sup>): 3046, ν(CH<sub>ar</sub>); 2953, 2921, 2850, ν(CH<sub>al</sub>); 1627, 1596, 1446, 1412, ν(C=C<sub>ar</sub>); 806, 745, 727, γ(C-H<sub>ar</sub>).

ESI-MS(*m/z*): calculated for C<sub>44</sub>H<sub>48</sub>N<sub>4</sub>S<sub>2</sub> [M]<sup>+</sup> = 696.33, found [M + H]<sup>+</sup> = 697.20.

2,5-Bis(4-(3,6-ditert-butyl-9H-carbazol-9-yl)phenyl)thiazolo[5,4-*d*]thiazole (TTP-CzB). It was obtained from 4-(3,6-ditert-butyl-9H-carbazol-9-yl)benzaldehyde (0.62 g, 1.59 mmol) and dithiooxamide (0.095 g, 0.80 mmol) by the same procedure as TT-EHCz. Yield 0.21 g (32%), mp 276–278 °C.

<sup>1</sup>H NMR (400 MHz, CDCl<sub>3</sub>) δ 8.20–8.25 (m, 2H); 8.15 (s, 4H); 8.02 (dd, *J*<sub>1</sub> = 7.9 Hz, *J*<sub>2</sub> = 5.4 Hz, 2H); 7.72 (t, *J* = 7.4 Hz, 2H); 7.44–7.51 (m, 8H); 7.19 (t, *J* = 8.2 Hz, 2H); 1.48 (s, 36H).

<sup>13</sup>C NMR (101 MHz, CDCl<sub>3</sub>) δ 143.47; 140.46; 138.72; 132.07; 128.47; 128.38; 127.82; 126.82; 123.84; 123.77; 116.48; 116.41; 116.26; 109.27; 34.79; 32.01.

FTIR (cm<sup>−1</sup>): 3056, ν(CH<sub>ar</sub>); 2953, 2900, 2863, ν(CH<sub>al</sub>); 1601, 1487, 1470, 1448, ν(C=C<sub>ar</sub>); 834, 812, 763, γ(C-H<sub>ar</sub>).

ESI-MS(*m/z*): calculated for C<sub>56</sub>H<sub>56</sub>N<sub>4</sub>S<sub>2</sub> [M]<sup>+</sup> = 848.39, found [M + H]<sup>+</sup> = 849.55.

2,5-Bis(4-(3,7-ditert-butyl-10H-phenothiazin-10-yl)phenyl)thiazolo[5,4-*d*]thiazole (TTP-PTB). It was obtained from 4-(3,7-ditert-butyl-10H-phenothiazin-10-yl)benzaldehyde (0.56 g, 1.20 mmol) and

dithiooxamide (0.11 g, 0.92 mmol) by the same procedure as TT-EHCz. Yield 0.20 g (24%).

<sup>1</sup>H NMR (400 MHz, CDCl<sub>3</sub>) δ 8.04 (d, *J* = 8.4 Hz, 4H); 7.33 (d, *J* = 8.4 Hz, 4H); 7.24 (d, *J* = 1.2 Hz, 4H); 7.09 (dd, *J*<sub>1</sub> = 8.5 Hz, *J*<sub>2</sub> = 1.2 Hz, 4H); 6.71 (d, *J* = 8.5 Hz, 4H); 1.28 (s, 36H).

<sup>13</sup>C NMR (101 MHz, CDCl<sub>3</sub>) δ 168.34; 150.82, 147.31; 145.52; 140.43; 130.46, 128.12; 125.82; 124.76; 124.64; 124.03; 120.2; 34.33; 31.28.

FTIR (cm<sup>−1</sup>): 3052, ν(CH<sub>ar</sub>); 2959, 2901, 2863, ν(CH<sub>al</sub>); 1595, 1506, 1477, 1447, ν(C=C<sub>ar</sub>); 1266, 1182, ν(C-N<sub>ar</sub>); 864, 809, 724, 672 γ(C-H<sub>ar</sub>).

ESI-MS(*m/z*): calculated for C<sub>56</sub>H<sub>56</sub>N<sub>4</sub>S<sub>4</sub> [M]<sup>+</sup> = 912.34, found [M]<sup>+</sup> = 912.90.

2,5-Bis(4-(3,6-dimethoxy-9H-carbazol-9-yl)phenyl)thiazolo[5,4-*d*]thiazole (TTP-CzM). It was obtained from 4-(3,6-dimethoxy-9H-carbazol-9-yl)benzaldehyde (0.70 g, 2.11 mmol) and dithiooxamide (0.12 g, 1.00 mmol) by the same procedure as TT-EHCz. Yield 0.25 g (33%), mp 215–217 °C.

<sup>1</sup>H NMR (400 MHz, CDCl<sub>3</sub>) δ 8.23 (d, *J* = 8.1 Hz, 4H); 7.71 (d, *J* = 8.2 Hz, 4H); 7.57 (s, 4H); 7.44 (d, *J* = 8.9 Hz, 4H); 7.07 (dd, *J*<sub>1</sub> = 9.0, *J*<sub>2</sub> = 1.1 Hz, 4H); 3.97 (s, 12H).

<sup>13</sup>C NMR (101 MHz, CDCl<sub>3</sub>) δ 168.11; 154.41; 140.24; 135.71; 131.96; 127.88; 126.73; 124.14; 115.32; 110.80; 103.07; 56.12.

FTIR (cm<sup>−1</sup>): 3025, ν(CHAR); 2932, 2892, 2836, ν(CH<sub>al</sub>); 1600, 1521, 1468, 1429, ν(C=Car); 833, 802, 785, γ(C-H<sub>ar</sub>).

ESI-MS(*m/z*): calculated for C<sub>44</sub>H<sub>32</sub>N<sub>4</sub>S<sub>2</sub> [M]<sup>+</sup> = 744.19, found [M]<sup>+</sup> = 744.49.

**Characterizations.** A Bruker Avance III [400 MHz (<sup>1</sup>H), 101 MHz (<sup>13</sup>C)] apparatus was used at room temperature for recording of <sup>1</sup>H NMR and <sup>13</sup>C NMR spectra. Chemical shifts (δ) are reported in ppm referenced to tetramethylsilane or to the internal solvent signal. MS analysis was recorded on a Waters ZQ (Waters, Milford, Massachusetts). IR spectra were recorded in transmission mode using a Spectrum GX FTIR spectrometer (PerkinElmer) using potassium bromide for the formation of pellets. UV absorption spectra were measured with a Lambda 35 UV/vis spectrometer (PerkinElmer) and a Vertex 70 Bruker spectrometer equipped with an ATR attachment with a diamond crystal over frequencies of 600–3500 cm<sup>−1</sup> with a resolution of 5 cm<sup>−1</sup> over 32 scans. Fluorescence (FL) spectra were recorded using a PerkinElmer LS 55 DSC. Measurements were carried out using a DSC Q2000. TGA was performed on a TGA Q50. The TGA and DSC curves were recorded in a nitrogen atmosphere at a heating rate of 10 °C/min. The CV measurements were carried out by a three-electrode assembly cell from Bio-Logic SAS and a micro-Autolab Type III potentiostat–galvanostat. The working electrode was a glassy carbon with the surface of 0.12 cm<sup>2</sup>. The reference electrode and the counter electrode were Ag/Ag<sup>+</sup> 0.01 M and Pt wire, respectively. The solutions with the concentration of 10<sup>−3</sup> M of the compounds in argon-purged dichloromethane (Fluka) with tetrabutylammonium perchlorate (TBAP; 0.1 M) as electrolyte were used for the CV measurements. Ionization potentials of films under an air atmosphere were measured by methods of photoelectron emission spectrometry. The samples for it were fabricated by the technique of thermal vacuum deposition onto fluorine-doped tin oxide-coated glass substrates. An ASBN-D130-CM-deep UV deuterium light source, a 6517B Keithley electrometer, and a CM110 1/8m monochromator were used for measurement of photoelectron emission spectra. Charge mobility values were studied by the time-of-flight (TOF) method. Various positive and negative external voltages (*U*) were applied to the samples using a 6517B electrometer (Keithley) to check hole and electron transports in the layers at the different electric fields. A TDS 3032C oscilloscope (Tektronix) was used to record the photocurrent transients of holes or electrons. Charge mobilities were estimated by the formula  $\mu = d^2/(U \times t_{tr})$ , where *t*<sub>tr</sub> is the transit time, *d* is the thickness of a layer, and *U* is the applied voltage over the sample.

**Device Fabrication.** The inverted PSCs were fabricated with the architecture of glass/ITO/HSL/Cs<sub>0.18</sub>FA<sub>0.82</sub>Pb(I<sub>0.8</sub>Br<sub>0.2</sub>)<sub>3</sub>/PEAI/PC<sub>61</sub>BM/BCP/Ag. Indium tin oxide (ITO) substrates were precleaned in an ultrasonic bath, sequentially with abstergent aqueous



solution, deionized water, acetone, and isopropyl alcohol, for 20 min each, and then dried under a stream of N<sub>2</sub>. HSLs include 2PACz, compound TTP-DPA, and 2PACz/TTP-DPA. A novel HSL of thiazolo[5,4-*d*]thiazole was spin-cast (5000 rpm, 30 s) on ITO. A self-assembled layer of 2PACz as HSL was spin-cast (3000 rpm, 30 s) on ITO and then baked at 100 °C for 10 min. The 2PACz precursor solution was prepared by dissolving 2PACz in ethanol at a concentration of 1 mg/mL and was placed in an ultrasonic bath for 15 min before being used. For interfacial engineering between 2PACz and perovskite, the derivative of thiazolo[5,4-*d*]thiazole (i.e., TTP-DPA) was spin-cast (5000 rpm, 30 s) on the top of 2PACz. The thiazolo[5,4-*d*]thiazoles were prepared by dissolving in chloroform. The precursor<sup>73</sup> solution for Cs<sub>0.18</sub>FA<sub>0.82</sub>Pb(I<sub>0.8</sub>Br<sub>0.2</sub>)<sub>3</sub> was prepared by dissolving 172 mg of FAI, 30 mg of CsCl, 110 mg of PbBr<sub>2</sub>, and 354 mg of PbI<sub>2</sub> in 1 mL of DMF:DMSO (4:1 in volume). The perovskite layer was deposited on the substrate in a two-step manner: first at 1000 rpm for 10 s and then at 5000 rpm for 30 s. During the second step, chlorobenzene (0.15 mL) was dropped on the spinning substrate; the sample was then annealed at 150 °C for 30 min. For the PEAI surface passivation, PEAI dissolved in IPA at a concentration of 1.5 mg/mL was spin-coated (5000 rpm, 30 s) on the top of the perovskite, followed by annealing at 100 °C for 1 min. For the electron transport layer, a solution of PC<sub>61</sub>BM in chlorobenzene (20 mg/mL) was spin-coated (2000 rpm, 30 s) on the top of the PEAI layer. For the hole-blocking layer, a solution of BCP in IPA (0.5 mg/mL) was spin-coated (6000 rpm, 10 s) onto the PC<sub>61</sub>BM layer. Finally, the devices were completed by evaporating Ag (100 nm) in a vacuum chamber; the active area of this electrode was fixed at 10 mm<sup>2</sup>, defined by the cross overlap of the 5 mm-wide-patterned ITO bar and the 2 mm-wide Ag bar deposited through a metal mask.

**Measurements.** Device performance data were collected within a glovebox. The current–voltage (*I*–*V*) characteristics of the devices were measured employing a computer-controlled Keithley 2400 source measurement unit (SMU) and a Dyesol simulator (AAA Class Solar Simulators) under AM 1.5 illumination (100 mW/cm<sup>2</sup>). The light intensity was calibrated using a standard Si reference cell and a KG-5 filter. EQE spectra were recorded using an Enlitech QE-R spectral response measurement system to standardize the current densities of the devices. PL spectra were acquired using an Edinburgh FLS1000 PL spectrometer, employing an excitation wavelength of 550 nm. TCSPC spectra were also recorded using an Edinburgh FLS1000 PL spectrometer with a pulse laser featuring a wavelength of 447 nm. The laser operated with a 500 ns excitation duration. The comprehensive characterization platform Paios (Fluxim AG) was employed to assess the optoelectronic properties of PSCs, including photo-CELIV, TPC, and TPV measurements. Crystallinity information was obtained using a Malvern Panalytical Empyrean X-ray diffractometer with Cu K $\alpha$  radiation ( $\lambda$  = 0.1542 nm) and a step size of 0.02°. The static contact angle measurements were recorded using a first 10 Å/FTA-1000B apparatus. SEM images were recorded on a HITACHI S-5200 SEM.

## CONCLUSIONS

Six donor-disubstituted TT derivatives were designed and synthesized. All the compounds exhibited high thermal stability. They showed 5% weight loss temperatures higher than 397 °C. TT containing two Cz or PTZ donor units with *tert*-butyl substituents showed the highest glass transition temperature values of 130 and 187 °C, respectively. The compounds were characterized by locally excited absorption bands caused by TT with a weak effect of intermolecular charge-transfer absorption in the visible region. Ionization potentials of the solid layers of the compounds estimated by photoelectron emission spectrometry in air ranged from 4.93 to 5.67 eV. Almost balanced hole and electron transports with mobilities of  $3.97 \times 10^{-4}$  and  $6.69 \times 10^{-4}$  cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>, respectively, were obtained for triphenylamino-substituted

thiazolo[5,4-*d*]thiazole. The highest hole mobility reaching  $1.63 \times 10^{-3}$  cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup> was observed for the derivative of TT and dimethoxy-substituted phenyl Cz. The layer of TT with hexyloxy-substituted triphenylamino substituent (TTP-DPA) was used for the preparation of HSL and interlayer for wide-band-gap Cs<sub>0.18</sub>FA<sub>0.82</sub>Pb(I<sub>0.8</sub>Br<sub>0.2</sub>)<sub>3</sub> PSCs. The optimized PSCs utilizing HSL of 2PACz/TTP-DPA HSL demonstrate maximum power conversion efficiencies of 19.1 and 37.0% under one-sun and 3000 K LED (1000 lx) illuminations, respectively, surpassing those observed control devices with HSL of 2PACz. These results underscore the potential of the D–A–D-type derivative of TT for interface modification as a practical and efficient approach to enhance passivation and contact properties of PSCs, highlighting their suitability as materials for HSLs.

## ASSOCIATED CONTENT

### Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acsami.4c04105>.

DSC graphs of TT derivatives; TOF signals for vacuum-deposited films of TT compounds; additional photo-physical data including PL spectra of TT materials in dilute toluene, THF, and chloroform solutions; <sup>1</sup>H spectra of synthesized materials TT-EHCz, TTP-CzB, TTP-PTB, and TTP-CzM; water contact angle and DIM contact angle measurements; device performance of the PSCs, including PSCs and iPSCs (PDF)

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## Author Contributions

#A.D. and Z.-E.S. contributed equally to this work. The manuscript was written through contributions of all authors. All authors have given approval to the final version of the manuscript.

## Notes

The authors declare no competing financial interest.

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